

## KBJ4005G - KBJ410G

KBJ

Min

24.80

14.70

17.20

0.90

7.30

3.10 Ø

3.30

1.50

9.30

2.50

3.40

4.40

0.60

All Dimensions in mm

4.00 Nominal

Max

25.20

15.30

17.80

1.10

7.70

3.40 Ø

3.70

1.90

9.70

2.90

3.80

4.80

0.80

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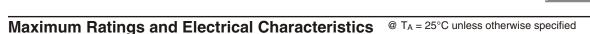
## 4.0A GLASS PASSIVATED BRIDGE RECTIFIER

## **Features**

- Glass Passivated Die Construction
- High Case Dielectric Strength of 1500V<sub>RMS</sub>
- Low Reverse Leakage Current
- Surge Overload Rating to 120A Peak
- Ideal for Printed Circuit Board Applications
- Plastic Material UL Flammability Classification 94V-0
- UL Listed Under Recognized Component Index, File Number E94661

## **Mechanical Data**

- Case: Molded Plastic
- Terminals: Plated Leads, Solderable per MIL-STD-202, Method 208
- Polarity: Molded on Body
- Mounting: Through Hole for #6 Screw
- Mounting Torque: 5.0 in-lbs Maximum
- Approx. Weight: 4.6 grams
- Marking: Type Number



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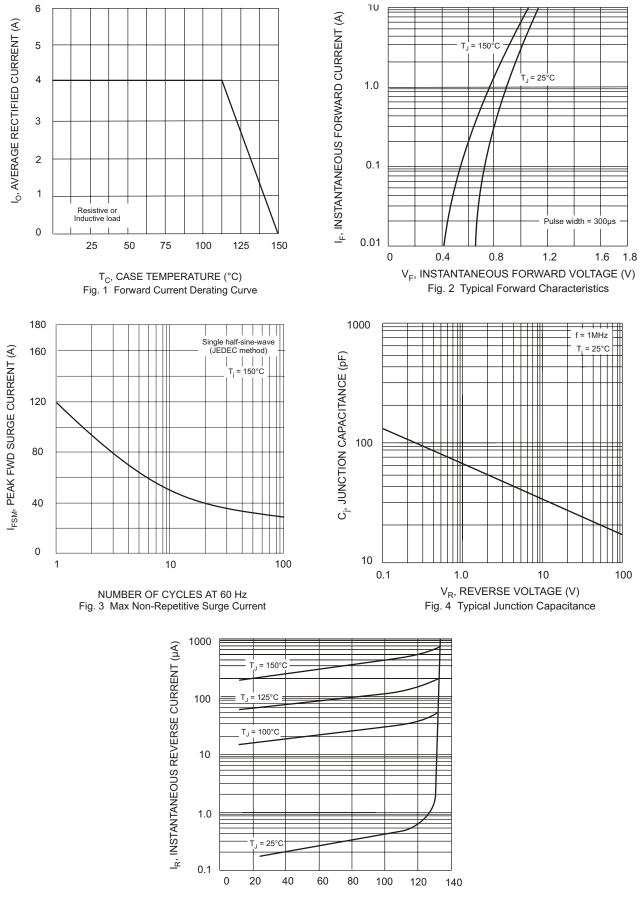
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	KBJ 4005G	KBJ 401G	KBJ 402G	KBJ 404G	KBJ 406G	KBJ 408G	KBJ 410G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Average Rectified Output Current @ T <sub>C</sub> = 115°C	Ιο	4.0							Α
Non-Repetitive Peak Forward Surge Current, 8.3 ms single half-sine-wave superimposed on rated load (JEDEC method)	I <sub>FSM</sub>	120							А
Forward Voltage per element @ I <sub>F</sub> = 2.0A	VFM	1.0						V	
Peak Reverse Current $@T_C = 25^{\circ}C$ at Rated DC Blocking Voltage $@T_C = 125^{\circ}C$	I <sub>RM</sub>	5.0 500							μA
Typical Junction Capacitance per Element (Note 1)	Cj	40							pF
Typical Thermal Resistance (Note 2)	R <sub>0JC</sub>	5.5						°C/W	
Operating and Storage Temperature Range	Tj, T <sub>STG</sub>	-65 to +150							°C

Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

2. Thermal resistance from junction to case per element. Unit mounted on 300 x 300 x 1.6mm aluminum plate heat sink.





PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 5 Typical Reverse Characteristics